

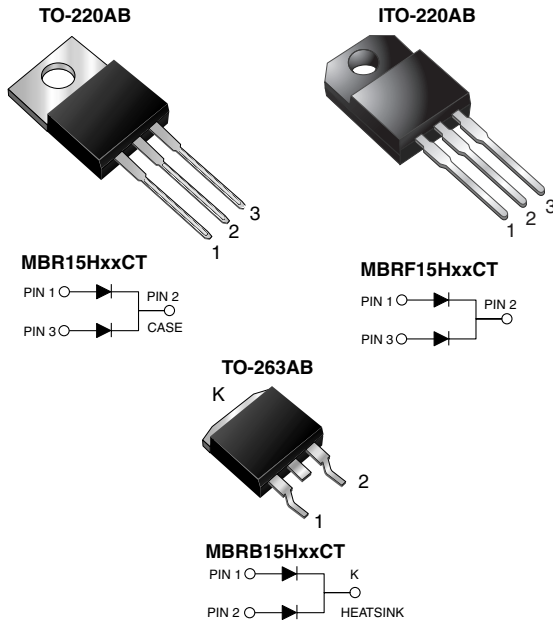


New Product
MBR(F,B)15H35CT thru MBR(F,B)15H60CT

Vishay General Semiconductor

Dual Common-Cathode Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



FEATURES

- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB and ITO-220AB package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	7.5 A x 2
V_{RRM}	35 V to 60 V
I_{FSM}	150 A
V_F	0.55 V, 0.61 V
I_R	50 μ A
T_J max.	175 °C

MAXIMUM RATINGS ($T_C = 25$ °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR15H35CT	MBR15H45CT	MBR15H50CT	MBR15H60CT	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	35	45	50	60	V
Working peak reverse voltage	V_{RWM}	35	45	50	60	V
Maximum DC blocking voltage	V_{DC}	35	45	50	60	V
Max. average forward rectified current total device per diode (Fig. 1)	$I_{F(AV)}$	15 7.5				A
Non-repetitive avalanche energy per diode at 25 °C, $I_{AS} = 4$ A, $L = 10$ mH	E_{AS}	80				mJ
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	150				A
Peak repetitive reverse surge current per diode at $t_p = 2.0$ μ s, 1 kHz	I_{RRM}	1.0		0.5		A
Peak non-repetitive reverse energy (8/20 μ s waveform)	E_{RSM}	20		10		mJ

New Product

MBR(F,B)15H35CT thru MBR(F,B)15H60CT



Vishay General Semiconductor

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR15H35CT	MBR15H45CT	MBR15H50CT	MBR15H60CT	UNIT
Electrostatic discharge capacitor voltage human body model: C = 100 F, R = 1.5 kΩ	V _C	25				kV
Voltage rate of change (rated V _R)	dV/dt	10 000				V/μs
Operating junction temperature range	T _J	- 65 to + 175				°C
Storage temperature range	T _{STG}	- 65 to + 175				°C
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500				V

ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	MBR15H35CT MBR15H45CT		MBR15H50CT MBR15H60CT		UNIT
				TYP.	MAX.	TYP.	MAX.	
Maximum instantaneous forward voltage per diode ⁽¹⁾	I _F = 7.5 A	T _J = 25 °C	V _F	-	0.63	-	0.73	V
	I _F = 7.5 A	T _J = 125 °C		0.50	0.55	0.58	0.61	
	I _F = 15 A	T _J = 25 °C		-	0.75	-	0.87	
	I _F = 15 A	T _J = 125 °C		0.61	0.66	0.68	0.72	
Maximum reverse current at rated V _R per diode ⁽²⁾		T _J = 25 °C T _J = 125 °C	I _R	- 3.0	50 10	- 2.0	50 10	μA mA

Notes:

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT	
Maximum thermal resistance per diode	R _{θJC}	3.0	5.0	3.0	°C/W	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	MBR15H45CT-E3/45	1.85	45	50/tube	Tube
ITO-220AB	MBRF15H45CT-E3/45	1.99	45	50/tube	Tube
TO-263AB	MBRB15H45CT-E3/45	1.35	45	50/tube	Tube
TO-263AB	MBRB15H45CT-E3/81	1.35	81	800/reel	Tape and reel
TO-220AB	MBR15H45CTHE3/45 ⁽¹⁾	1.85	45	50/tube	Tube
ITO-220AB	MBRF15H45CTHE3/45 ⁽¹⁾	1.99	45	50/tube	Tube
TO-263AB	MBRB15H45CTHE3/45 ⁽¹⁾	1.35	45	50/tube	Tube
TO-263AB	MBRB15H45CTHE3/81 ⁽¹⁾	1.35	81	800/reel	Tape and reel

Note:

- (1) Automotive grade AEC Q101 qualified



New Product MBR(F,B)15H35CT thru MBR(F,B)15H60CT

Vishay General Semiconductor

RATINGS AND CHARACTERISTICS CURVES

($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

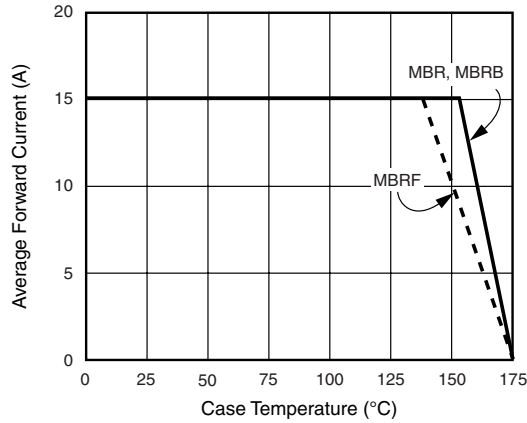


Figure 1. Forward Derating Curve Per Diode

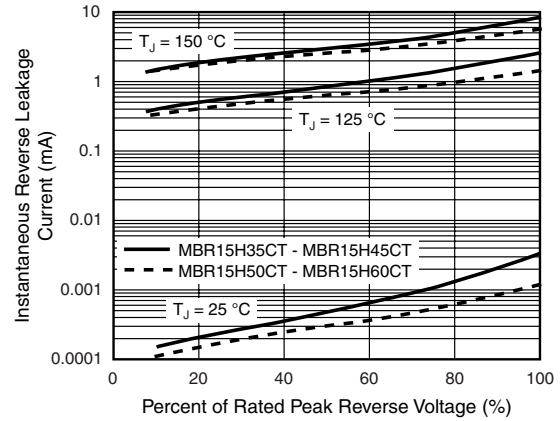


Figure 4. Typical Reverse Characteristics Per Diode

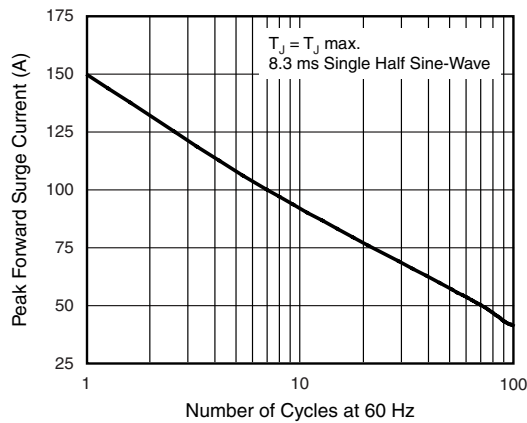


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

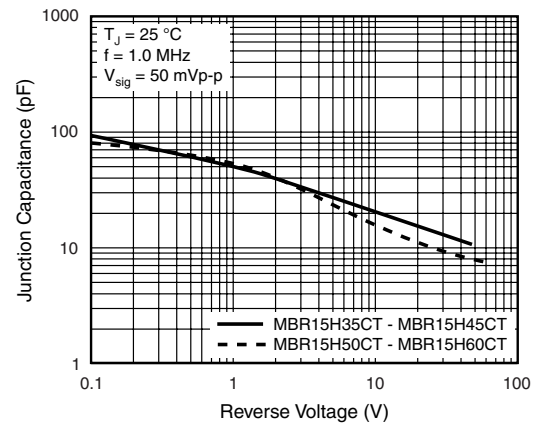


Figure 5. Typical Junction Capacitance Per Diode

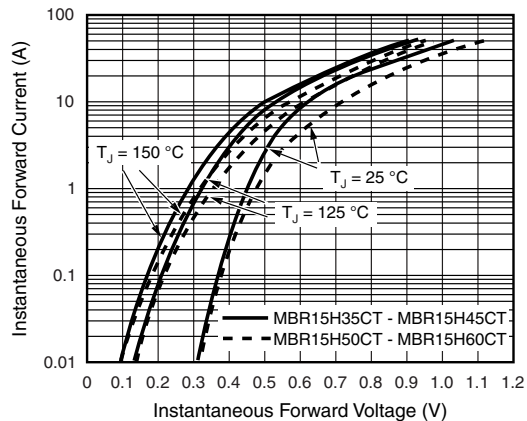


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

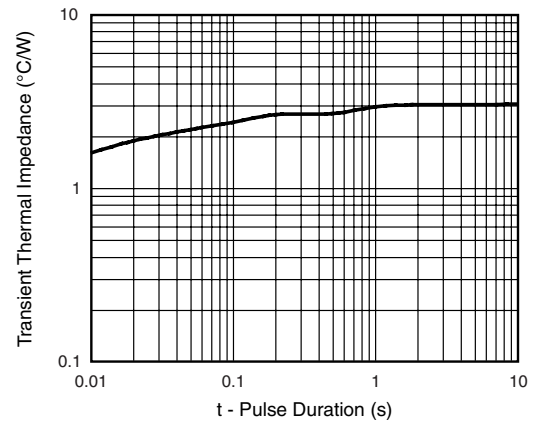


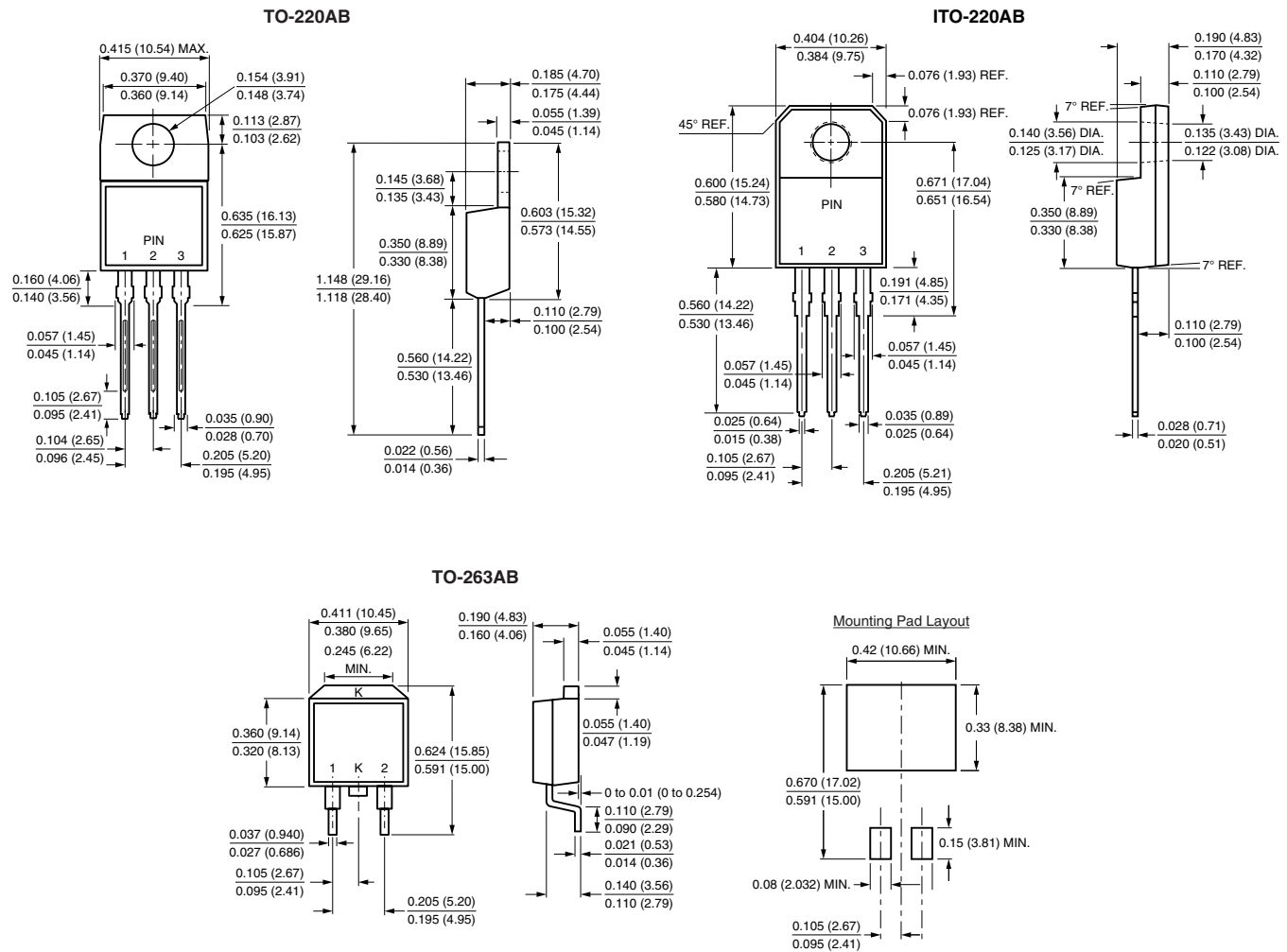
Figure 6. Typical Transient Thermal Impedance Per Diode

New Product MBR(F,B)15H35CT thru MBR(F,B)15H60CT

Vishay General Semiconductor



PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.